### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:	Art Unit:	Not Assigned
FURUKAWA, et al.	Examiner:	Not Assigned
Serial No: Not Assigned; Parent 10/281,852		
Filed: June 23, 2003		

Element and Manufacturing Method Thereof

# TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT

Semiconductor Light Emitting

Mail Stop: PATENT APPLICATION Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

#### Dear Sirs:

For:

1.	The information disclosure statement submitted herewith is being filed within three months of the filing date of the application other than a continued prosecution application, or within three months of the date of entry into the national stage of an international application, or before the mailing date of a first Office Action on the merits, or before the mailing of a first Office action after the filing of a request for continued examination under §1.114, whichever event occurs last. 37 C.F.R. §1.97(b).
2.	The information disclosure statement transmitted herewith is being filed <i>after</i> the period specified in §1.97(b), but <i>before</i> the mailing date of a final action under §1.113, or a notice of allowance under §1.311, or an action that otherwise closes prosecution in the application, whichever occurs first. A statement specified in §1.97(e) or a fee set forth in §1.17(p) is included. 37 C.F.R. §1.97(c).
	§1.97(e) STATEMENT
	I, the person signing below, state:
	that each item of information contained in the information disclosure statement was first cited in the attached communication from a foreign patent office in a counterpart foreign application and that the communication is dated not more than three months prior to the filing of the statement. 37 C.F.R. §1.97(e)(1).
	OR
	that no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart

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foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of information contained in the information disclosure statement was known to any individual designated in §1.56(c) more than three months prior to the filing of the statement. 37 C.F.R. §1.97(e)(2).

### OR FEE Attached is a fee set forth in 37 C.F.R. §1.17(p) for submission of an information disclosure statement under §1.97(c). (\$180.00). [OR:] Please charge the fee set forth in 37 C.F.R. §1.17(p) for submission of an information disclosure statement under §1.97(c) (\$180.00) to Deposit Account No. 50-1314. A copy of this petition is enclosed. The information disclosure statement transmitted herewith is being filed after the period specified in §1.97(c), but before, or simultaneously with the payment of the issue fee. A statement specified in §1.97(e) and a fee set forth in §1.17(p) are included. 37 C.F.R. §1.97(d). §1.97(e) STATEMENT I, the person signing below, state: that each item of information contained in the information disclosure statement was first cited in the attached communication from a foreign patent office in a counterpart foreign application and that the communication is dated not more than three months prior to the filing of the statement. 37 C.F.R. §1.97(e)(1). OR that no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of information contained in the information disclosure statement was known to any individual designated in §1.56(c) more than three months prior to the filing of the statement. 37 C.F.R. §1.97(e)(2). AND FEE Attached is a fee set forth in 37 C.F.R. §1.17(p) for submission of an information disclosure statement under §1.97(d). (\$180.00).

4. A If it should be determined that for any reason either an insufficient fee or an excessive has been paid, please charge any insufficiency or credit any overpayment necessary to ensure consideration of the information disclosure statement for the above-identified application to Deposit Account No. 50-1314. A copy of this petition is enclosed.

C.F.R. § 1.98(d), of submitted in pare	Gerence(s) is in the enclosed Form PTO-1449. Pursuant to 37 copies of the listed reference(s) are not provided since they were ent application Serial No. <u>09/745.250</u> , the benefit of the filing laimed herein under 35 U.S.C. § 120.						
NO	N-ENGLISH LANGUAGE REFERENCES						
Enclosed is a search report for a counterpart application. The search report Examine has provided comments on the relevancy of any non-English language references cite in the search report.							
☐ The specification incorporates comments on the relevancy of Non-English languate references.							
☐ Set forth below are comments provided by the applicant's home country counsel on the relevancy of non-English language references:							
	Respectfully submitted, HOGAN A HARTSON L.L.P.						
Date: June 23, 2003	By: Anthony J. Orler						
Biltmore Tower 500 South Grand Avenue Los Angeles, CA 90071 Telephone: (213) 337-6 Facsimile: (213) 337-6	Registration No. 41,232 Attorney for Applicant(s)  700						

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**FORM PTO-1449** 

## INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional) Appli 81788.0251 Not A
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**Applicant** 

FURUKAWA, et al.

Filing Date June 23, 2003 Group Art Unit Not Assigned

		U.S. PATE	NT DOCUMENTS	3					
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DA			
	6,404,125	06-2002	Garbuzov et al.	313	499				
	6,340,824	01-2002	Komoto et al.	257	99				
	5,998,925	12-1999	Shimizu et al.	313	503				
	5,813,752	09-1998	Singer et al.	362	293				
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	F	OREIGN PA	TENT DOCUMEN	ITS					
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	S Translation YES NO			
	2000-082849	03/21/00	JAPAN			123	"		
	11-087778	03/30/99	JAPAN						
	10-012916	01/16/98	JAPAN						
		-							
	OTHER DOCUME	NTS (Including )	 Author, Title, Date, Pe	ertinent Pages	, Etc.)	<u> </u>			
Ti A	hick GzN Epitaxial Growth with Lo pplied Physics 36, Part 2, No. 7B,	w Dislocation De L899 (1997)	nsity by Hydride Vapor	Phase Epitaxy	/ – USUI, et al./	Japanese J	ournal		
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**DATE CONSIDERED** 

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.